# 60 V, 2 A, Low V<sub>CE(sat)</sub> PNP Transistor

ON Semiconductor's  $e^2$ PowerEdge family of low V<sub>CE(sat)</sub> transistors are miniature surface mount devices featuring ultra low saturation voltage (V<sub>CE(sat)</sub>) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and LED lightning, power management...etc. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

#### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- NSV60200SMTWTBG Wettable Flanks Device
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ )

Rating	Symbol	Мах	Unit
Collector–Emitter Voltage	V <sub>CEO</sub>	60	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	6	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	2	А
Collector Current – Peak	I <sub>CM</sub>	3	А

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{ hetaJA}$	69	°C/W
Total Power Dissipation @ $T_A = 25^{\circ}C$ (Note 1)	PD	1.8	W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

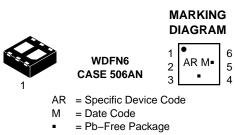
1. Per JESD51-7 with 100 mm<sup>2</sup> pad area and 2 oz. Cu.



## **ON Semiconductor®**

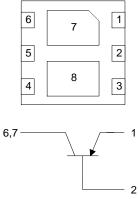
www.onsemi.com

# 60 Volt, 2 Amp PNP Low V<sub>CE(sat)</sub> Transistor



(Note: Microdot may be in either location)

## PIN CONNECTIONS



(Pins 3,4,5,8 are not connected)

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSS60200SMTTBG	WDFN6 (Pb–Free)	3000/Tape & Reel
NSV60200SMTWTBG	WDFN6 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### Table 1. ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ unless otherwise noted)

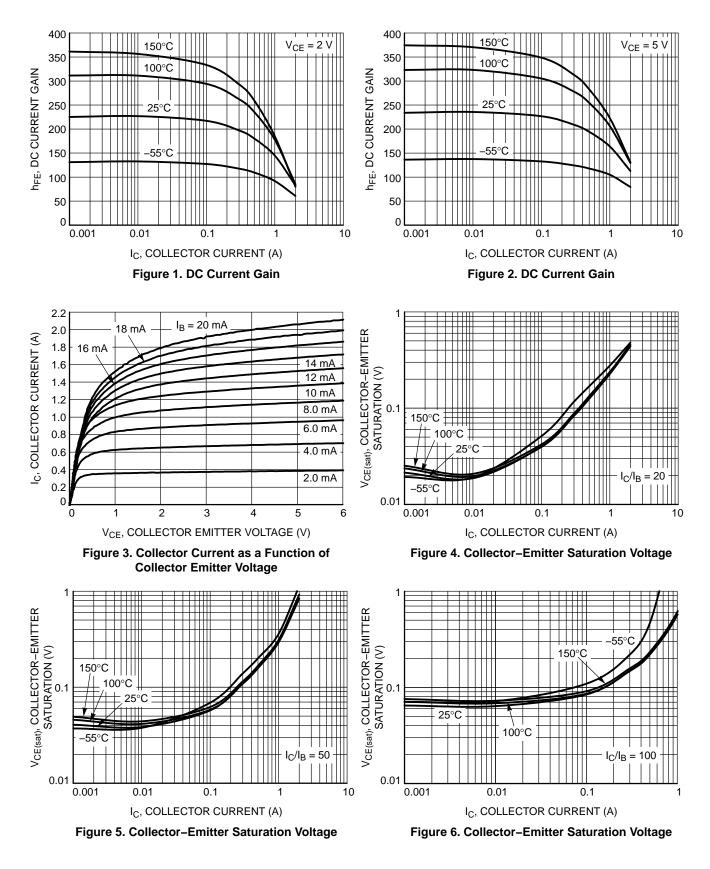
Characteristic	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ( $I_C = -10$ mA, $I_B = 0$ )	V <sub>(BR)CEO</sub>	-60			V
Collector-Base Breakdown Voltage (Ic = $-0.1$ mA, I <sub>E</sub> = $0$ )	V <sub>(BR)CBO</sub>	-80		1	V
Emitter–Base Breakdown Voltage ( $I_E = -0.1 \text{ mA}, I_C = 0$ )	V <sub>(BR)EBO</sub>	-6			V
Collector Cutoff Current (V <sub>CB</sub> = $-60$ V, I <sub>E</sub> = $0$ )	I <sub>CBO</sub>			-100	nA
Emitter Cutoff Current ( $V_{BE} = -5.0 \text{ V}$ )	I <sub>EBO</sub>			-100	nA
ON CHARACTERISTICS					
DC Current Gain (Note 2) ( $I_C = -100 \text{ mA}, V_{CE} = -2.0 \text{ V}$ ) ( $I_C = -500 \text{ mA}, V_{CE} = -2.0 \text{ V}$ ) ( $I_C = -1 \text{ A}, V_{CE} = -2.0 \text{ V}$ ) ( $I_C = -2 \text{ A}, V_{CE} = -2.0 \text{ V}$	h <sub>FE</sub>	150 120 90 40	230 180 140 80		
Collector-Emitter Saturation Voltage (Note 2) ( $I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$ ) ( $I_C = -700 \text{ mA}, I_B = -7.0 \text{ mA}$ ) ( $I_C = -1 \text{ A}, I_B = -50 \text{ mA}$ ) ( $I_C = -1 \text{ A}, I_B = -100 \text{ mA}$ ) ( $I_C = -2 \text{ A}, I_B = -200 \text{ mA}$ )	V <sub>CE(sat)</sub>		-0.115 -0.295 -0.250 -0.200 -0.365	-0.160 -0.420 -0.350 -0.300 -0.450	V
Base – Emitter Saturation Voltage (Note 2) ( $I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$ ) ( $I_C = -1 \text{ A}, I_B = -50 \text{ mA}$ ) ( $I_C = -1 \text{ A}, I_B = -100 \text{ mA}$ )	V <sub>BE(sat)</sub>			-1.0 -1.0 -1.1	V
Base–Emitter Turn–on Voltage (Note 2) ( $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ )	V <sub>BE(on)</sub>			-0.9	V
DYNAMIC CHARACTERISTICS					
Output Capacitance ( $V_{CB} = 10 \text{ V}, f = 1.0 \text{ MHz}$ )	C <sub>obo</sub>		18		pF
Cutoff Frequency ( $I_C = 50 \text{ mA}, V_{CE} = 2.0 \text{ V}, f = 100 \text{ MHz}$ )	f <sub>T</sub>		155		MHz
SWITCHING TIMES					
Delay Time (V <sub>CC</sub> = -10 V, I <sub>C</sub> = -0.5 A, I <sub>B1</sub> = -25 mA, I <sub>B2</sub> = 25 mA)	t <sub>d</sub>		15		ns
Rise Time (V <sub>CC</sub> = $-10$ V, I <sub>C</sub> = $-0.5$ A, I <sub>B1</sub> = $-25$ mA, I <sub>B2</sub> = $25$ mA)	t <sub>r</sub>		13		ns
Storage Time (V <sub>CC</sub> = $-10$ V, I <sub>C</sub> = $-0.5$ A, I <sub>B1</sub> = $-25$ mA, I <sub>B2</sub> = $25$ mA)	t <sub>s</sub>		360		ns
				+	

Fall Time (V\_{CC} = -10 V, I\_C = -0.5 A, I\_{B1} = -25 mA, I\_{B2} = 25 mA) t<sub>f</sub> Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Condition: Pulse Width =  $300 \ \mu$ sec, Duty Cycle  $\leq 2\%$ 

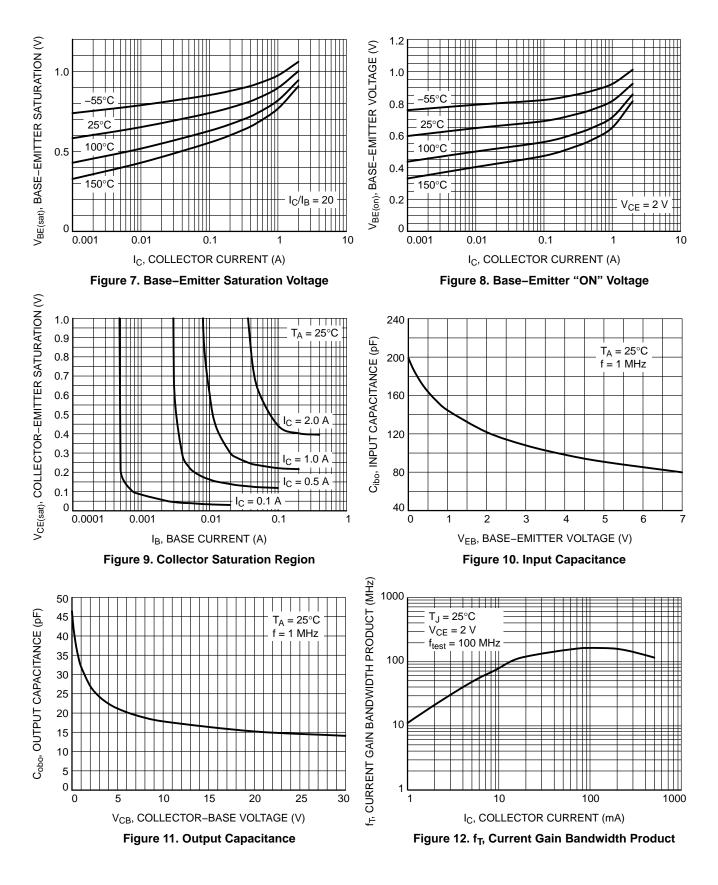
22

ns

# **TYPICAL CHARACTERISTICS**



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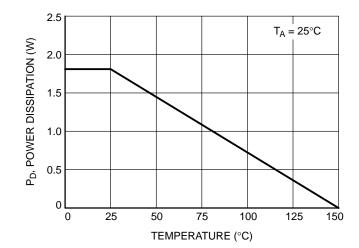


Figure 13. Power Derating

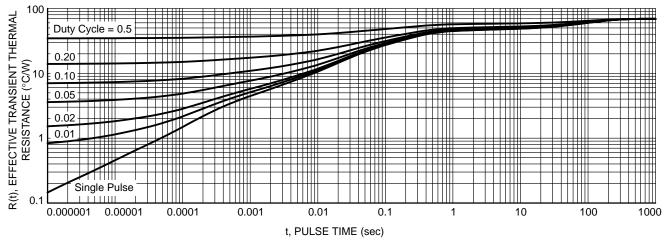
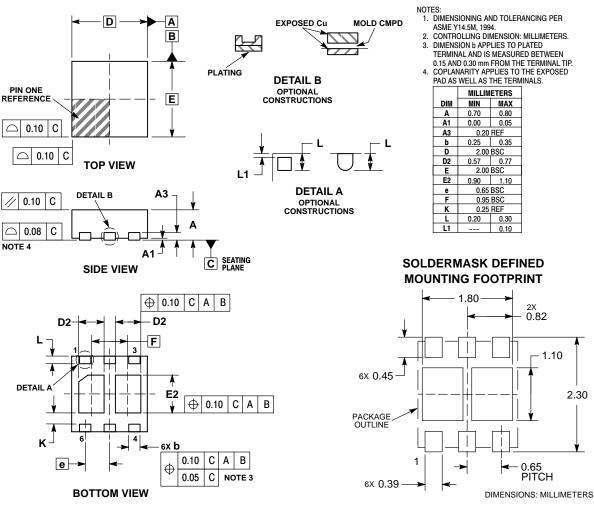


Figure 14. Thermal Resistance by Transistor

#### PACKAGE DIMENSIONS

# WDFN6 2x2, 0.65P CASE 506AN

ISSUE G



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